

GT10G131(TE12L,Q)

GT10G131(TE12L,Q) Information

www.prisener.com	GT10G131(TE12L,Q) Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - IGBTs - Single IGBT 400V 1W 8-SOIC 8-SOIC (0.173", 4.40mm Width) For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



GT10G131(TE12L,Q) Specifications

Manufacturer Part Number	GT10G131(TE12L,Q)	
Manufacturer	Toshiba Semiconductor and Storage	
Category	Discrete Semiconductor Products	
	Transistors - IGBTs - Single	
Package	8-SOIC (0.173", 4.40mm Width)	
Series	-	
IGBT Type	-	
Voltage - Collector Emitter Breakdown (Max)	400V	
Current - Collector (Ic) (Max)	-	
Current - Collector Pulsed (Icm)	200A	
Vce(on) (Max) @ Vge, Ic	2.3V @ 4V, 200A	
Power - Max	1W	
Switching Energy	-	
Input Type	Standard	
Gate Charge	-	
Td (on/off) @ 25°C	3.1µs/2µs	
Test Condition	-	
Reverse Recovery Time (trr)	-	
Operating Temperature	150°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	8-SOIC (0.173", 4.40mm Width)	
Supplier Device Package	8-SOP (5.5x6.0)	
	Report errors?	

GT10G131(TE12L,Q) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

GT10G131(TE12L,Q) Payment Methods





If you have any question about GT10G131(TE12L,Q), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com